Vishay Semiconductors

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Ultrafast Rectifier, 2 x 6 A FRED Pt®



LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | | | |
|----------------------------------|-----------------|--|--|--|--|
| I _{F(AV)} | 2 x 6 A | | | | |
| V _R | 600 V | | | | |
| V _F at I _F | 0.89 V | | | | |
| t _{rr} | 45 ns | | | | |
| T _J max. | 175 °C | | | | |
| Package | SMPD (TO-263AC) | | | | |
| Circuit configuration | Common cathode | | | | |

FEATURES

- Ultrafast recovery time, reduced Q_{rr}, and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

| ABSOLUTE MAXIMUM RATINGS | | | | | | | |
|---|------------|--------------------|---|--------|-------|--|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Peak repetitive reverse voltage | | V _{RRM} | | 600 | V | | |
| Average restified forward average | per device | I _{F(AV)} | T _{solder pad} = 156 °C | 12 | • | | |
| Average rectified forward current | per diode | | | 6 | | | |
| Non repetitive peak aurge aurgent | per device | | $T_{\rm e} = 25$ °C. 6 ma aquera pulsa | 200 | A | | |
| Non-repetitive peak surge current per diode | | IFSM | T _J = 25 °C, 6 ms square pulse | 105 | | | |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|--|----------------------------------|--|------|------|------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | I _R = 100 μA | 600 | - | - | | |
| Forward voltage, per diade | V _F | I _F = 6 A | - | 1.05 | 1.3 | V | |
| Forward voltage, per diode | | I _F = 6 A, T _J = 150 °C | - | 0.89 | 1.1 | | |
| Reverse leakage current, per diode | I _R | V _R = V _R rated | - | - | 5 | | |
| | | T _J = 150 °C, V _R = V _R rated | - | 20 | 150 | μΑ | |
| Junction capacitance, per diode | CT | V _R = 600 V | - | 8 | - | pF | |

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HALOGEN



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| DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified) | | | | | | | |
|---|------------------------------|--|--|------|------|------|-------------|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | MIN. | TYP. | MAX. | UNITS |
| | | $I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50$ | A/ μ s, V _R = 30 V | - | 45 | - | |
| Poweree receivery time | + | I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A | | - | - | 60 | |
| Reverse recovery time | t _{rr} | T _J = 25 °C | | - | 65 | - | - ns - A |
| | | T _J = 125 °C | I _F = 6 A, dI _F /dt = 500 A/µs, V _B = 400 V | - | 90 | - | |
| Deels receivers ourrent | I _{RRM} | T _J = 25 °C | | - | 10 | - | |
| Peak recovery current | | T _J = 125 °C | | - | 15 | - | |
| | 0 | T _J = 25 °C | 1 '' | - | 350 | - | nC |
| Reverse recovery charge | Q_{rr} $T_J = 125^{\circ}$ | T _J = 125 °C | | - | 680 | - | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|---|-----------------------------------|----------------------------|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -55 | - | +175 | °C |
| Thermal resistance, per diode junction to mount | R _{thJM} | | - | 1.8 | 2.5 | °C/W |
| Approximate weight | | | | 0.55 | | g |
| Approximate weight | | | | 0.02 | | oz. |
| Marking device | | Case style SMPD (TO-263AC) | | 1201 | DU06 | |



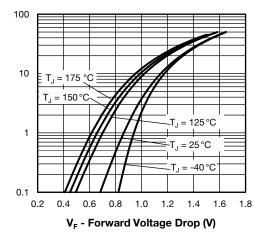


Fig. 1 - Typical Forward Voltage Drop Characteristics

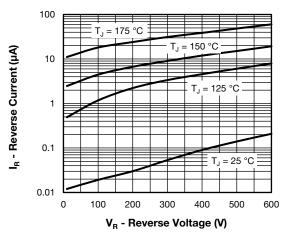


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

VS-12CDU06HM3

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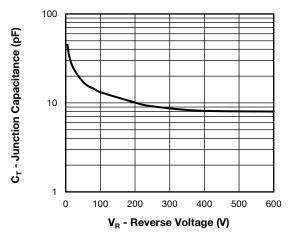


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

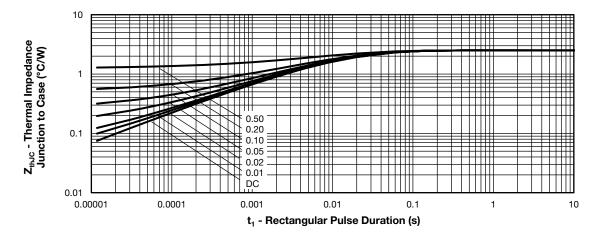
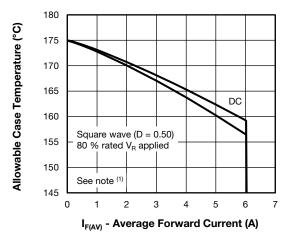
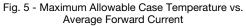


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

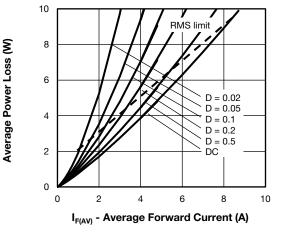


Fig. 6 - Forward Power Loss Characteristics

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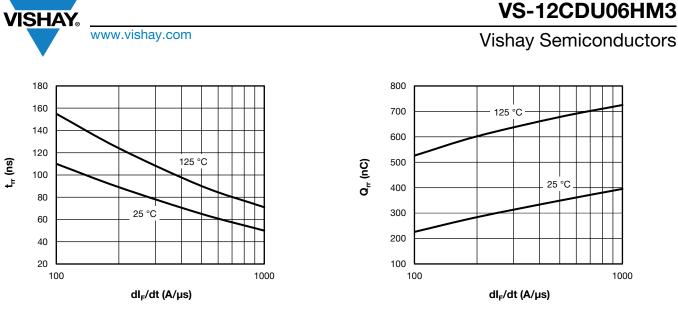


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt



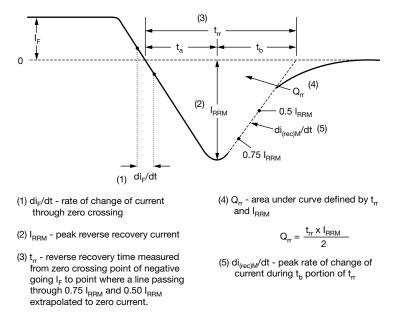


Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

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SHAY

| | | | | _ | | | | |
|-------------|-----|--------|-----------|-----------|----------|---------|----------|---------|
| Device code | VS- | 12 | С | D | U | 06 | н | M3 |
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 |
| | 1 | - Visl | hay Sen | nicondu | ctors pr | oduct | | |
| | 2 | - Cur | rent rati | ing (12 A | A) | | | |
| | 3 | - Circ | cuit con | figuratio | n: | | | |
| | | C = | commo | on catho | de | | | |
| | 4 | - D= | SMPD | packag | е | | | |
| | 5 | - Pro | cess typ | ce, | | | | |
| | | U = | ultrafas | st recove | ery | | | |
| | 6 | - Vol | tage coo | de (06 = | 600 V) | | | |
| | 7 | - H= | AEC-Q | 101 qua | alified | | | |
| | 8 | - M3 | = halog | en-free, | RoHS- | complia | ant, and | termina |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|--|------|------------------------------------|--|--|--|--|
| PREFERRED P/N | N QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION | | | | | | |
| VS-12CDU06HM3/I | 2000 | 2000 | 13" diameter plastic tape and reel | | | | |

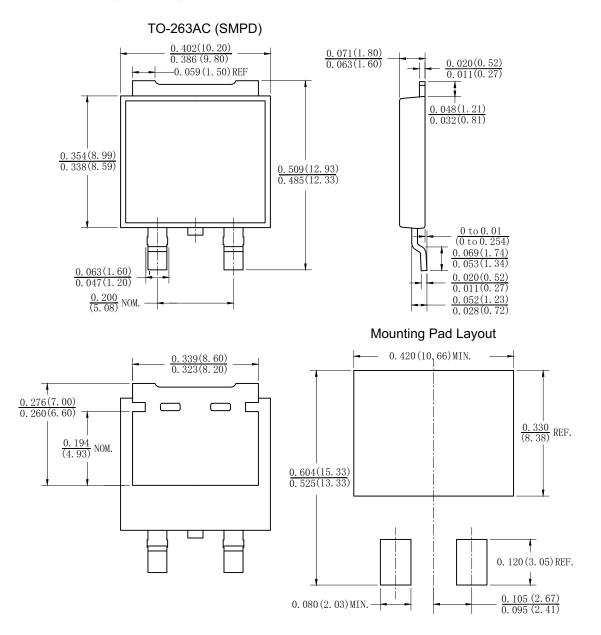
| LINKS TO RELATED DOCUMENTS | | | | | |
|----------------------------|--------------------------|--|--|--|--|
| Dimensions | www.vishay.com/doc?95604 | | | | |
| Part marking information | www.vishay.com/doc?95566 | | | | |
| Packaging information | www.vishay.com/doc?88869 | | | | |





TO-263AC (SMPD)

DIMENSIONS in inches (millimeters)





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